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Part 16-4: Microwave integrated circuits – Switches
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INTERNATIONAL ELECTROTECHNICAL COMMISSION

SEMICONDUCTOR DEVICES –

Part 16-4: Microwave integrated circuits –
Switches

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The technical content is therefore identical to the base edition and its amendment and has been prepared for user convenience. A vertical line in the margin shows where the base publication has been modified by amendment 1. Additions and deletions are displayed in red, with deletions being struck through.

International Standard IEC 60747-16-4 has been prepared by subcommittee 47E: Discrete semiconductor devices, of IEC technical committee 47: Semiconductor devices.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

The committee has decided that the contents of the base publication and its amendments will remain unchanged until the stability date indicated on the IEC web site under "<http://webstore.iec.ch>" in the data related to the specific publication. At this date, the publication will be

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SEMICONDUCTOR DEVICES –

Part 16-4: Microwave integrated circuits – Switches

1 Scope

This part of IEC 60747 provides new measuring methods, terminology and letter symbols, as well as essential ratings and characteristics for integrated circuit microwave switches.

There are many combinations for RF ports in switches, such as SPST (single pole single throw), SPDT (single pole double throw), SP3T (single pole triple throw), DPDT (double pole double throw), etc. Switches in this standard are based on SPDT. However, this standard is applicable to the other types of switches.

2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

~~IEC 60617-12, Graphical symbols for diagrams – Part 12: Binary logic elements~~

~~IEC 60617-13, Graphical symbols for diagrams – Part 13: Analogue elements~~

IEC 60617, Graphical symbols for diagrams

~~IEC 60747-1(1983), Semiconductor devices – Discrete devices and integrated circuits – Part 1: General~~
~~Amendment 3 (1996)~~

IEC 60747-1:2006, Semiconductor devices – Part 1: General

IEC 60747-4, Semiconductor devices – Discrete devices – Part 4: Microwave devices

IEC 60747-16-1:2001, Semiconductor devices – Part 16-1: Microwave integrated circuits – Amplifiers
Amendment 1 (2007)¹

IEC 60748-2, Semiconductor devices – Integrated circuits – Part 2: Digital integrated circuits

IEC 60748-3, Semiconductor devices – Integrated circuits – Part 3: Analogue integrated circuits

IEC 60748-4, Semiconductor devices – Integrated circuits – Part 4: Interface integrated circuits

IEC 61340-5-1:2007, Electrostatics – Part 5-1: Protection of electronic devices from electrostatic phenomena – General requirements

IEC/TR 61340-5-2:2007, Electrostatics – Part 5-2: Protection of electronic devices from electrostatic phenomena – User guide

¹ There exists a consolidated edition 1.1 published in 2007, including the base publication (2001) and its Amendment 1 (2007).

3 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

Terms related to electrical characteristics

3.1

insertion loss

L_{ins}

ratio of the ~~out~~ input power to the output power at the switched on port, ~~to the input power~~ in the linear region of the power transfer curve P_O (dBm) = $f(P_i)$

NOTE 1 In this region, ΔP_O (dBm) = ΔP_i (dBm).

NOTE 2 Usually the insertion loss is expressed in decibels.

3.2

isolation

L_{iso}

ratio of the ~~out~~ input power to the output power at the switched off port, ~~to the input power~~ in the linear region of the power transfer curve P_O (dBm) = $f(P_i)$

NOTE 1 In this region, ΔP_O (dBm) = ΔP_i (dBm).

NOTE 2 Usually the isolation is expressed in decibels.

3.3

return loss

L_{ret}

ratio of the incident power P_{inc} at the specified port to the reflected power P_{ref} at the same port in the linear region of the power transfer curve P_{ref} (dBm) = $f(P_{inc})$

NOTE 1 In this region, ΔP_{ref} (dBm) = ΔP_{inc} (dBm).

NOTE 2 Usually the return loss is expressed in decibels.

3.4

input power at 1 dB compression

$P_i(1\text{ dB})$

input power where the insertion loss increases by 1 dB compared with insertion loss in linear region

3.5

output power at 1 dB compression

$P_o(1\text{ dB})$

output power where the insertion loss increases by 1 dB compared with insertion loss in linear region

3.6

turn on time

t_{on}

interval between the lower reference point on the leading edge of the control voltage and the upper reference point on the leading edge of the envelope of the output voltage in the linear region of the power transfer curve P_O (dBm) = $f(P_i)$

NOTE In this region, ΔP_O (dBm) = ΔP_i (dBm).

3.7

turn off time

t_{off}

interval between the upper reference point on the trailing edge of the control voltage and the lower reference point on the trailing edge of the envelope of the output voltage in the linear region of the power transfer curve P_O (dBm) = $f(P_i)$

NOTE In this region, ΔP_O (dBm) = ΔP_i (dBm).

3.8 rise time

 $t_{r(\text{out})}$

interval between the lower reference point on the leading edge of the output voltage and the upper reference point on the leading edge of the envelope of the output voltage in the linear region of the power transfer curve P_o (dBm) = $f(P_i)$

NOTE In this region, ΔP_o (dBm) = ΔP_i (dBm).

3.9 fall time

 $t_{f(\text{out})}$

interval between the upper reference point on the trailing edge of the output voltage and the lower reference point on the trailing edge of the envelope of the output voltage in the linear region of the power transfer curve P_o (dBm) = $f(P_i)$

NOTE In this region, ΔP_o (dBm) = ΔP_i (dBm).

3.10 adjacent channel power ratio

 $P_{o(\text{mod})}/P_{\text{adj}}$

ratio of the total power in the specified carrier signal frequency band to total output power in the specified frequency band away from the specified carrier signal frequency, at the specified output power when the modulation signal is supplied

3.11

~~n-th order harmonic distortion ratio~~

 ~~$P_{n\text{th}}/P_1$~~ ~~See 3.14 of IEC 60747-16-1(2001).~~

nth order harmonic distortion ratio

 $P_1/P_{n\text{th}}$

See 3.14 of Amendment 1 of IEC 60747-16-1:2007.

IEC 60747-16-4:2004

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4 Essential ratings and characteristics

This clause gives ratings and characteristics required for specifying integrated circuit microwave switches.

4.1 Circuit identification and types

4.1.1 Designation and types

Identification of type (device name), category of circuit and technology applied should be given. Microwave switches comprise one category.

4.1.2 General function description

A general description of the function performed by the integrated circuit microwave switches and the features for the application should be made.

4.1.3 Manufacturing technology

The manufacturing technology, e.g. semiconductor monolithic integrated circuit, thin film integrated circuit, micro-assembly, etc. should be stated. This statement should include details of the semiconductor technologies such as Schottky-barrier diode, PIN diode, MESFET, Si bipolar transistor, etc.

IEC 60747-4 should be referred to for terminology and letter symbols, essential ratings and characteristics and measuring methods of such microwave devices.

4.1.4 Package identification

The following statements should be made:

- a) chip or packaged form;
- b) IEC and/or national reference number of the outline drawing, ~~or~~ or drawing of non-standard package including terminal numbering;
- c) principal package material, for example, metal, ceramic, plastic.

4.1.5 Main application

The main application should be stated. If the device has restrictive applications, these should be stated here.

4.2 Application description

Information on application of the integrated circuit and its relation to the associated devices should be given.

4.2.1 Conformance to system and/or interface information

It should be stated whether the integrated circuit conforms to an application system and/or an interface standard or a recommendation.

Detailed information concerning application systems, equipment and circuits such as VSAT systems, DBS receivers, microwave landing systems, etc. should also be given.

4.2.2 Overall block diagram

A block diagram of the applied systems should be given if necessary.

4.2.3 Reference data

The most important properties that permit comparison between derivative types should be given.

4.2.4 Electrical compatibility

It should be stated whether the integrated circuit is electrically compatible with other particular integrated circuits, or families of integrated circuits, or whether special interfaces are required.

Details should be given concerning the type of input and output circuits, e.g. input/output impedances, d.c. block, open-drain, etc. Interchangeability with other devices, if any, should also be given.

4.2.5 Associated devices

If applicable, the following should be stated:

- devices necessary for correct operation (list with type number, name and function);
- peripheral devices with direct interfacing (list with type number, name and function).

4.3 Specification of the function

4.3.1 Detailed block diagram – Functional blocks

A detail block diagram or equivalent circuit information of the integrated circuit microwave switches should be given. The block diagram should be composed of the following:

- a) functional blocks;
- b) mutual interconnections among the functional blocks;
- c) individual functional units within the functional blocks;
- d) mutual interconnections among the individual functional blocks;
- e) function of each external connection;
- f) inter-dependence between the separate functional blocks.

The block diagram should identify the function of each external connection and, where no ambiguity can arise, also show the terminal symbols and/or numbers. If the encapsulation has metallic parts, any connection to them from external terminals should be indicated. The connections with any associated external electrical elements should be stated, where necessary.

As additional information, the complete electrical circuit diagram can be reproduced, but not necessarily with indications of the values of the circuit components. The graphical symbol for the function shall be given. Rules governing such diagrams may be obtained from IEC 60617-12 or IEC 60617-13.

4.3.2 Identification and function of terminals

All terminals should be identified on the block diagram (supply terminals, input or output terminals, input/output terminals).

The terminal functions 1) to 4) should be indicated in a table as follows:

Terminal number	Terminal symbol	1) Terminal designation	2) Function	Function of terminal	
				3) Input/output identification	4) Type of input/output circuits

1) Terminal designation

A terminal designation to indicate the function of the terminal should be given. Supply terminals, ground terminals, blank terminals (with abbreviation NC), non-usable terminals (with abbreviation NU) should be distinguished.

2) Function

A brief indication of the terminal function should be given:

- each function of multi-role terminals, i.e. terminals having multiple functions;
- each function of integrated circuit selected by mutual pin connections, programming and/or application of function selection data to the function selection pin, such as mode selection pin.

3) Input/output identification

Input, output, input/output and multiplex input/output terminals should be distinguished.

4) Type of input/output circuits

The type of input and output circuit, e.g. input/output impedances, with or without d.c. block, etc., should be distinguished.

5) Type of ground

If the baseplate of the package is used as ground, this should be stated.